NSN 5961-00-936-3896

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-936-3896 **Inclosure Material:** Metal **Overall Length:** 0.520 inches **Overall Diameter:** 1.250 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-36 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 130.0 breakdown voltage, collector-to-base, emitter open and 10.0 breakdown voltage, emitter-to-base, collector open and 65.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 10.00 amperes forward current, average and 6.00 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 pin Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

NSN 5961-00-936-3896 Transistor - Page 2 of 2



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